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Jameco Part Number 1072487

8A, 1000V Ultrafast Diodes

The MUR8100E and RUR8100 are ultrafast diodes ($t_{rr} < 75\text{ns}$) with soft recovery characteristics. They have a low forward voltage drop and are of planar, silicon nitride passivated, ion-implanted, epitaxial construction.

These devices are intended for use as energy steering/clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and ultrafast recovery with soft recovery characteristics minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistor.

Formerly developmental type TA09617.

Ordering Information

PART NUMBER	PACKAGE	BRAND
MUR8100E	TO-220AC	MU8100
RURP8100	TO-220AC	RURP8100

NOTE: When ordering, use entire part number.

Symbol



Absolute Maximum Ratings $T_C = 25^\circ\text{C}$, Unless Otherwise Specified

	MUR8100E RURP8100	UNITS
Peak Repetitive Reverse Voltage	V_{RRM}	1000
Working Peak Reverse Voltage	V_{RWM}	1000
DC Blocking Voltage	V_R	1000
Average Rectified Forward Current ($T_C = 155^\circ\text{C}$)	$I_{F(AV)}$	8
Repetitive Peak Surge Current	I_{FRM}	16
(Square Wave 20kHz)		
Nonrepetitive Peak Surge Current	I_{FSM}	100
(Halfwave 1 Phase 60Hz)		
Maximum Power Dissipation	P_D	75
Avalanche Energy (See Figures 10 and 11)	E_{AVL}	20
Operating and Storage Temperature	T_{STG}, T_J	${}^\circ\text{C}$
	-55 to 175	

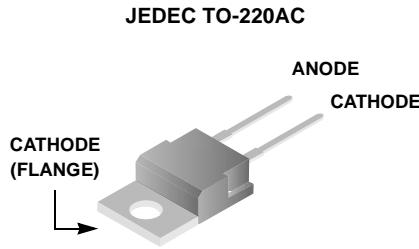
Features

- Ultrafast with Soft Recovery <75ns
- Operating Temperature 175°C
- Reverse Voltage 1000V
- Avalanche Energy Rated
- Planar Construction

Applications

- Switching Power Supply
- Power Switching Circuits
- General Purpose

Packaging



Electrical Specifications $T_C = 25^\circ\text{C}$, Unless Otherwise Specified.

SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNITS
V_F	$I_F = 8\text{A}$	-	-	1.8	V
	$I_F = 8\text{A}, T_C = 150^\circ\text{C}$	-	-	1.5	V
I_R	$V_R = 1000\text{V}$	-	-	100	μA
	$V_R = 1000\text{V}, T_C = 150^\circ\text{C}$	-	-	500	μA
t_{rr}	$I_F = 1\text{A}$	-	-	85	ns
	$I_F = 8\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	-	100	ns
t_a	$I_F = 8\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	50	-	ns
t_b	$I_F = 8\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	30	-	ns
Q_{RR}	$I_F = 8\text{A}, dI_F/dt = 200\text{A}/\mu\text{s}$	-	500	-	nC
C_J	$V_R = 10\text{V}, I_F = 0\text{A}$	-	30	-	pF
$R_{\theta JC}$		-	-	2.0	$^\circ\text{C}/\text{W}$

DEFINITIONS

V_F = Instantaneous forward voltage ($pw = 300\mu\text{s}$, $D = 2\%$).

I_R = Instantaneous reverse current.

t_{rr} = Reverse recovery time at $dI_F/dt = 100\text{A}/\mu\text{s}$ (See Figure 9), summation of $t_a + t_b$.

t_a = Time to reach peak reverse current at $dI_F/dt = 100\text{A}/\mu\text{s}$ (See Figure 9).

t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

Q_{RR} = Reverse recovery charge.

C_J = Junction Capacitance.

$R_{\theta JC}$ = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

Typical Performance Curves

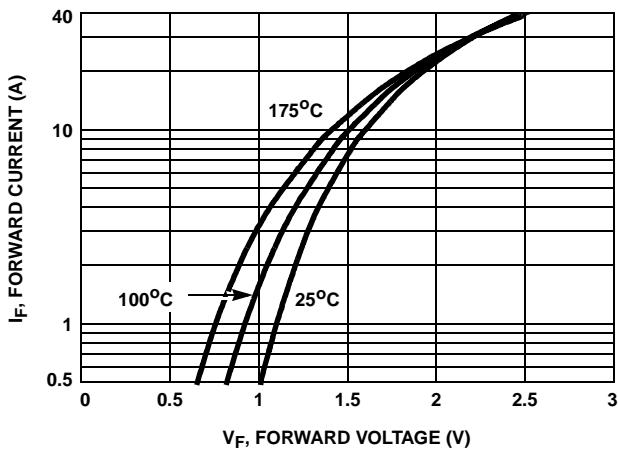


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

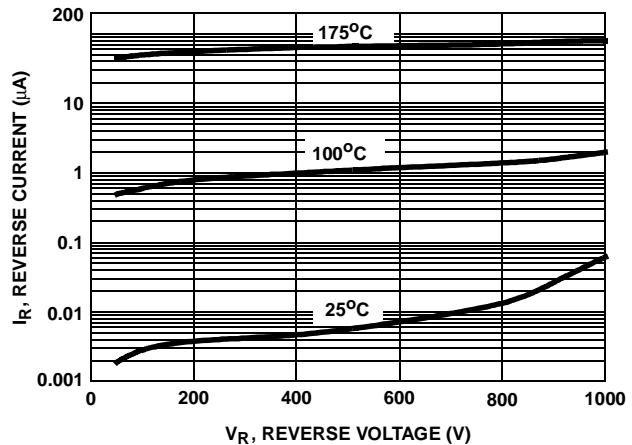


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

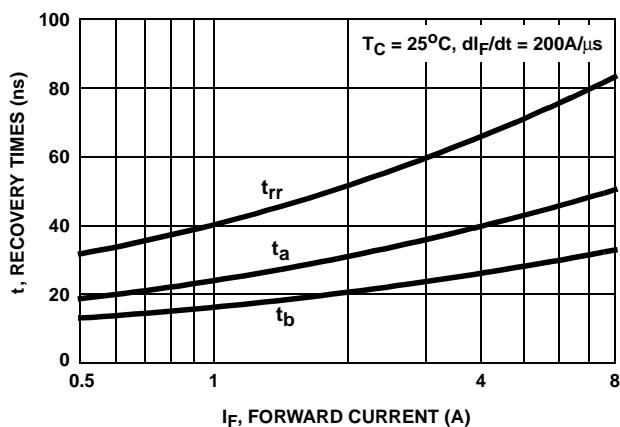


FIGURE 3. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

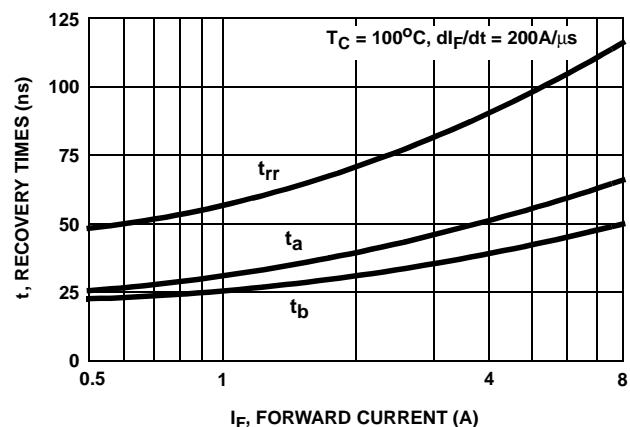


FIGURE 4. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

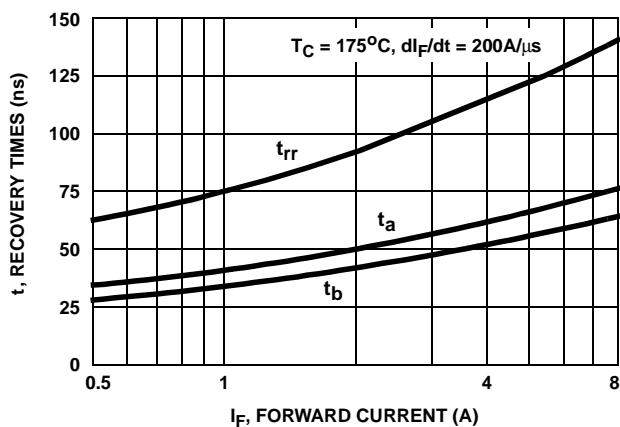


FIGURE 5. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

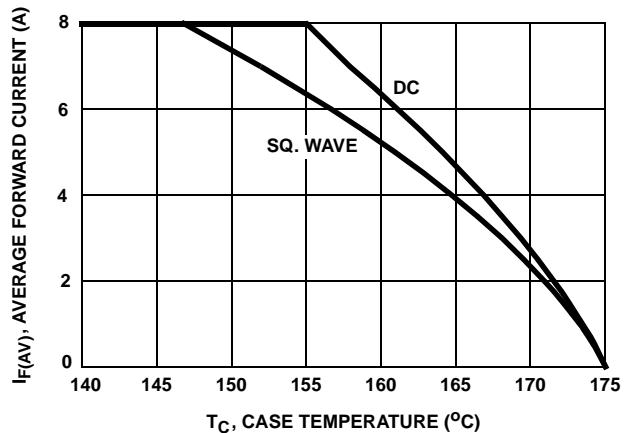


FIGURE 6. CURRENT DERATING CURVE

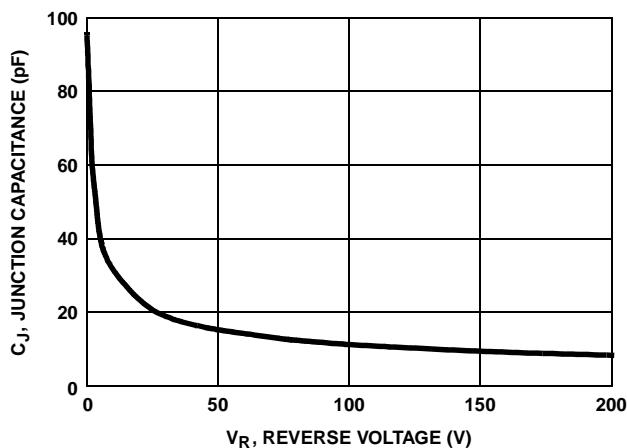


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

Test Circuits and Waveforms

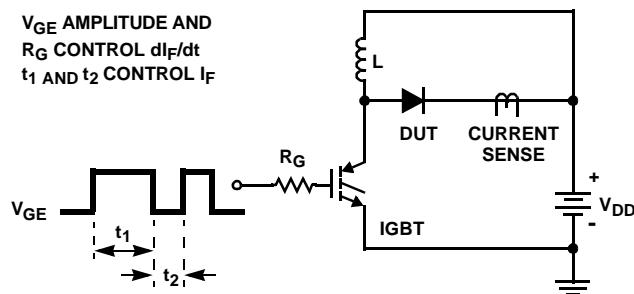


FIGURE 8. t_{rr} TEST CIRCUIT

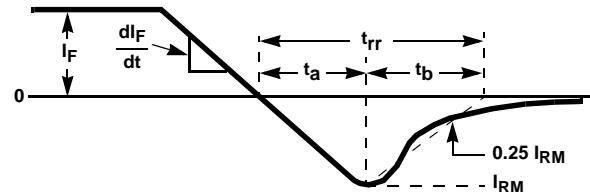


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

I = 1A
L = 40mH
R < 0.1Ω
E_{AVL} = 1/2LI² [V_{R(AVL)}/(V_{R(AVL)} - V_{DD})]
Q₁ = IGBT (BV_{CES} > DUT V_{R(AVL)})

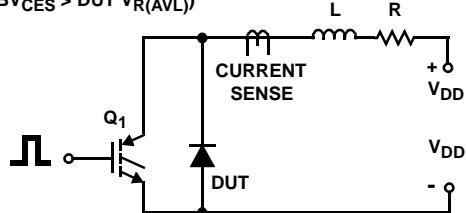


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

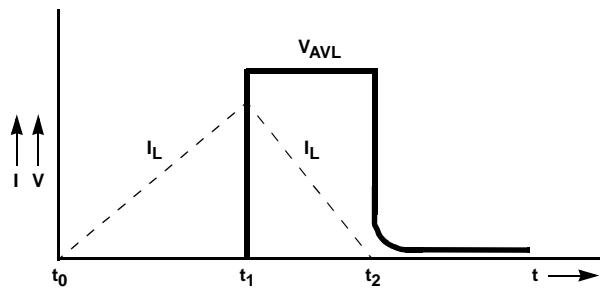


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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CROSSVOLT TM	FRFET TM	MicroPak TM	QFET TM	SuperSOT ^{TM-8}
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EcoSPARK TM	GTO TM	MSX TM	QT Optoelectronics TM	TinyLogic TM
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